

3.3V ABT Octal inverting buffer (3-State)

74LVT240

FEATURES

- Octal bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Power-up 3-State
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC JC40.2 Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model.

DESCRIPTION

The LVT240 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is an octal inverting buffer that is ideal for driving bus lines. The device features two Output Enables ($1\overline{OE}$, $2\overline{OE}$), each controlling four of the 3-State outputs.

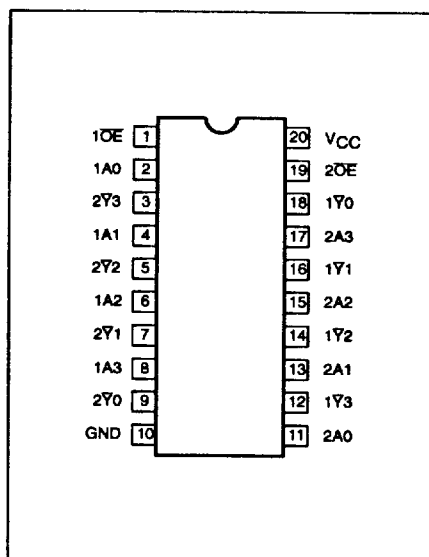
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}\text{C}$; $GND = 0V$	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay nA_x to nY_x	$C_L = 50\text{pF}$; $V_{CC} = 3.3V$	2.5	ns
C_{IN}	Input capacitance	$V_I = 0V$ or $3.0V$	4	pF
C_{OUT}	Output capacitance	Outputs disabled; $V_O = 0V$ or $3.0V$	8	pF
I_{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6V$	0.12	mA

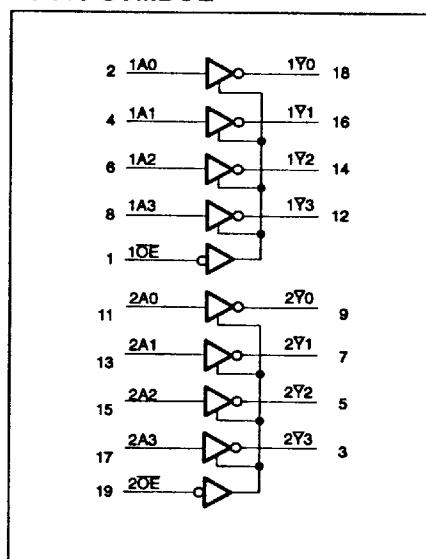
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DRAWING NUMBER
20-Pin Plastic Small Outline Large (300mil) (SOL)	-40°C to $+85^{\circ}\text{C}$	74LVT240D	SOT163-1
20-Pin Plastic Shrink Small Outline (SSOP) Type II	-40°C to $+85^{\circ}\text{C}$	74LVT240DB	SOT399-1
20-Pin Plastic Thin Shrink Small Outline (TSSOP) Type I	-40°C to $+85^{\circ}\text{C}$	74LVT240PW	SOT360-1

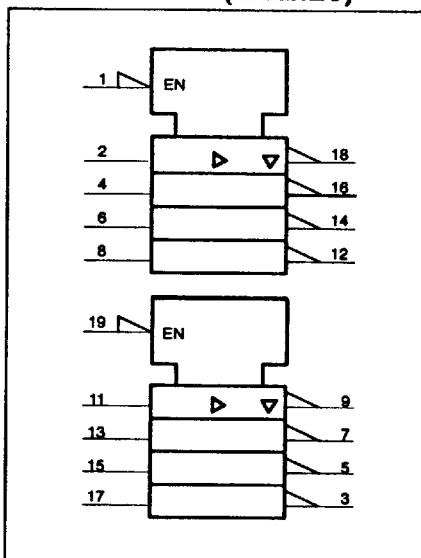
PIN CONFIGURATION



LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



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May 16, 1994

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FUNCTION TABLE

INPUTS		OUTPUTS
nOE	nAx	nYx
L	L	H
L	H	L
H	X	Z

H = High voltage level
 L = Low voltage level
 X = Don't care
 Z = High impedance "Off" state

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 4, 6, 8	1A0 – 1A3	Data inputs
11, 13, 15, 17	2A0 – 2A3	Data inputs
18, 16, 14, 12	1Y0 – 1Y3	Data outputs
9, 7, 5, 3	2Y0 – 2Y3	Data outputs
1, 19	1OE, 2OE	Output enables
10	GND	Ground (0V)
20	VCC	Positive supply voltage

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		–0.5 to +4.6	V
V _I	DC input voltage ³		–0.5 to +7.0	V
V _{OUT}	DC output voltage ³	Output in Off or High state	–0.5 to +7.0	V
I _{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	–64	
I _{IK}	DC input diode current	V _I < 0	–50	mA
I _{OK}	DC output diode current	V _O < 0	–50	mA
T _{stg}	Storage temperature range		–65 to 150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V _{CC}	DC supply voltage	2.7	3.6	V
V _I	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level input voltage		0.8	V
I _{OH}	High-level output current		–32	mA
I _{OL}	Low-level output current		32	mA
	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64	
Δt/Δv	Input transition rise or fall rate; outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	–40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				T _{amb} = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _I = -18mA			0.9	-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 2.7 to 3.6V; I _{OH} = -100μA		V _{CC} -0.2	V _{CC} -0.1		V
		V _{CC} = 2.7V; I _{OH} = -8mA		2.4	2.5		V
		V _{CC} = 3V; I _{OH} = -32mA		2	2.2		V
V _{OL}	Low-level output voltage	V _{CC} = 2.7V; I _{OL} = 100μA			0.1	0.2	V
		V _{CC} = 2.7V; I _{OL} = 24mA			0.3	0.5	
		V _{CC} = 3V; I _{OL} = 16mA			0.25	0.4	
		V _{CC} = 3V; I _{OL} = 32mA			0.3	0.5	
		V _{CC} = 3V; I _{OL} = 64mA			0.4	0.55	
I _I	Input leakage current	V _{CC} = 0 or 3.6V; V _I = 5.5V			1	10	μA
		V _{CC} = 3.6V; V _I = V _{CC} or GND	Control pins		±0.1	±1	
		V _{CC} = 3.6V; V _I = V _{CC}	Data pins ⁴		0.1	1	
		V _{CC} = 3.6V; V _I = 0			-1	-5	
I _{OFF}	Output off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V			1	±100	μA
I _{HOLD}	Bus hold current A inputs	V _{CC} = 3.0V; V _I = 0.8V	A inputs	75	150		μA
		V _{CC} = 3.0V; V _I = 2.0V		-75	-150		
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 3.0V			60	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	V _{CC} = ≤ 1.2V; V _O = 0.5V to V _{CC} ; V _I = GND or V _{CC} ; OE/OE = Don't care			±1	±100	μA
I _{OZH}	3-State output High current	V _{CC} = 3.6V; V _O = 3.0V			1	5	μA
I _{OZL}	3-State output Low current	V _{CC} = 3.6V; V _O = 0.5V			-1	-5	μA
I _{CC}	Quiescent supply current	V _{CC} = 3.6V; I _O = 0; V _I = V _{CC} or GND	Outputs High		0.12	0.19	mA
			Outputs Low		3	12	
			Outputs Disabled		0.12	0.19	
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 3.0 to 3.6V; One input at V _{CC} -0.6V; Other inputs at V _{CC} or GND			0.1	0.2	mA

NOTES:

1. All typical values are at $T_{amb} = 25^{\circ}\text{C}$.
2. This is the increase in supply current for each input at $V_{CC} - 0.6\text{V}$.
3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From $V_{CC} = 1.2\text{V}$ to $V_{CC} = 3.3\text{V} \pm 10\%$ a transition time of 100 μsec is permitted. This parameter is valid for $T_{amb} = 25^{\circ}\text{C}$.
4. Unused pins at V_{CC} or GND

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AC CHARACTERISTICS

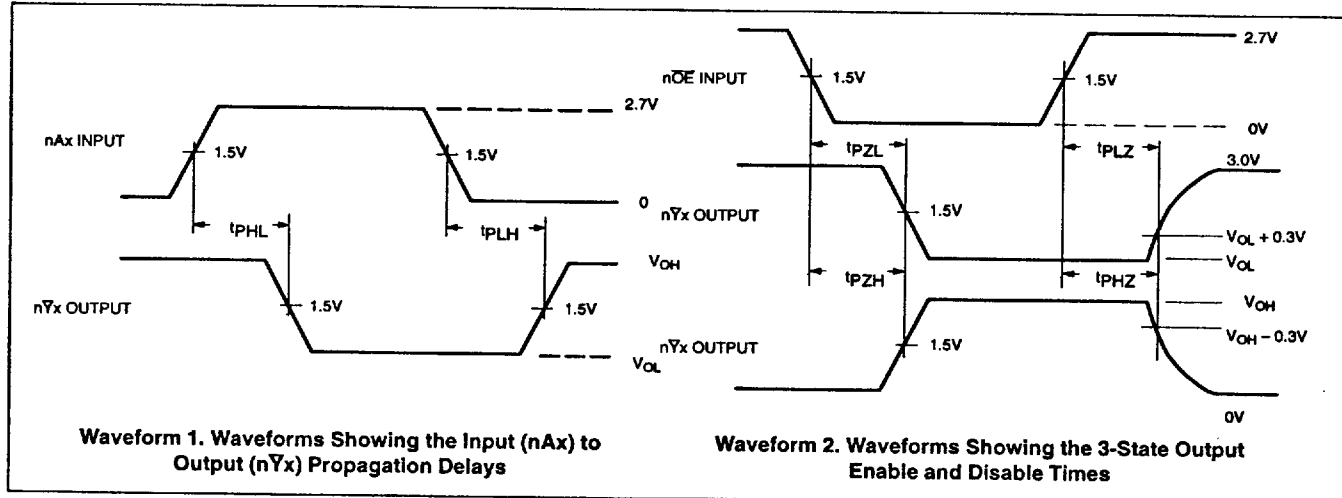
GND = 0V; $t_R = t_F = 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 500\Omega$; $T_{\text{amb}} = -40^\circ\text{C}$ to $+85^\circ\text{C}$.

SYMBOL	PARAMETER	WAVEFORM	LIMITS				UNIT
			$T_{\text{amb}} = -40^\circ\text{C}$ to $+85^\circ\text{C}$ $V_{\text{CC}} = +3.3\text{V} \pm 0.3\text{V}$			$V_{\text{CC}} = 2.7\text{V}$	
			MIN	TYP ¹	MAX	MAX	
t_{PLH} t_{PHL}	Propagation delay $n\text{Ax}$ to $n\text{Yx}$	1	1 1	2.5 2.5	4.3 4.3	5.2 5.0	ns
t_{PZH} t_{PZL}	Output enable time to High and Low level	2	1 1	3.7 3.1	5.2 5.2	6.3 6.7	ns
t_{PHZ} t_{PLZ}	Output disable time from High and Low level	2	2 1.6	3.4 3.2	5.6 5.1	6.3 5.6	ns

NOTE:

1. All typical values are at $V_{\text{CC}} = 3.3\text{V}$ and $T_{\text{amb}} = 25^\circ\text{C}$.

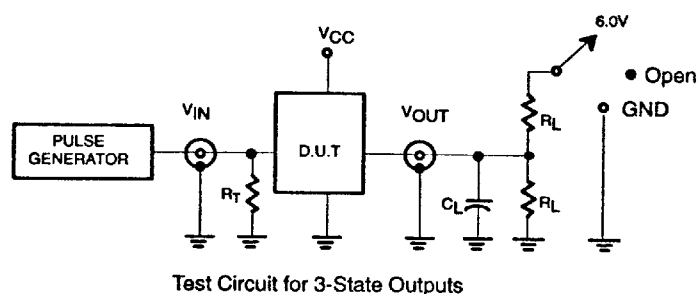
AC WAVEFORMS

 $V_M = 1.5\text{V}$, $V_{\text{IN}} = \text{GND}$ to 2.7V 

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TEST CIRCUIT AND WAVEFORMS



Test Circuit for 3-State Outputs

SWITCH POSITION

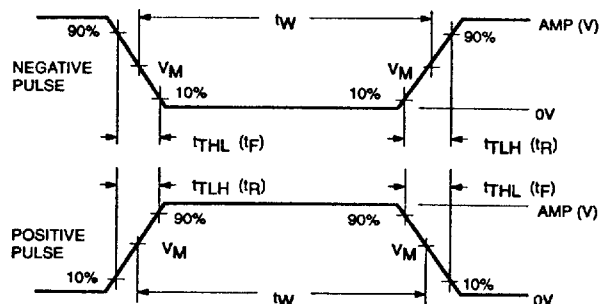
TEST	SWITCH
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6V
t_{PHZ}/t_{PZH}	GND

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.



$V_M = 1.5V$
Input Pulse Definition

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_W	t_R	t_F
74LVT	2.7V	$\leq 10\text{MHz}$	500ns	$\leq 2.5\text{ns}$	$\leq 2.5\text{ns}$